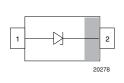


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Single ESD-Protection Diode in SOD-523





MARKING (example only)



Bar = cathode marking

X = date code

Y = type code (see table below)

DESIGN SUPPORT TOOLS AVAILABLE



FEATURES

- Compact SOD-523 package
- Low package height < 0.7 mm
- 1-line ESD-protection
- AEC-Q101 qualified
- Working range 5 V
- Low leakage current I_R < 0.1 μA
- Capacitance typical C_D = 12 pF
- ESD-protection acc. IEC 61000-4-2
 - ± 30 kV contact discharge
 - ± 30 kV air discharge
- Lead plating: Sn (e3)
 - soldering can be checked by standard vision inspection
 - (AOI = automated optical inspection)
 - no X-ray necessary
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912











ORDERING INFORMATION							
		ENVIRON					
PART NUMBER (EXAMPLE) AEC-Q1		RoHS COMPLIANT + LEAD (Pb)-FREE TERMINATIONS	TIN PLATED	8K PER 7" REEL (8 mm TAPE)	ORDERING CODE (EXAMPLE)		
		GREEN		MOQ = 8K/BOX			
VESD05B1-02V	-	G	3	-08	VESD05B1-02V-G3-08		
VESD05B1-02V	Н	G	3	-08	VESD05B1-02VHG3-08		

PACKAGE DATA						
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS
VESD05B1-02V	SOD-523	. н	1.32 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT		
Peak pulse current	Acc. IEC 61000-4-5, 8/20 µs/single shot	I _{PPM}	3.5	А		
Peak pulse power	Acc. IEC 61000-4-5, 8/20 µs/single shot	P _{PP}	40	W		
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	M	± 30	kV		
	Air discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	± 30	kV		
Operating temperature	perating temperature Junction temperature		-55 to +150	°C		
Storage temperature		T _{stg}	-55 to +150	°C		



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and inductance) of the protection device.

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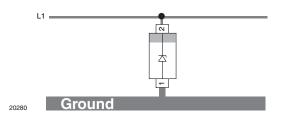
BIAs-MODE (bidirectional asymmetrical protection mode)

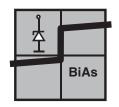
With the VESD05B1-02V one signal- or data-lines (L1) can be protected against voltage transients. With pin 1 connected to ground and pin 2 connected to a signal- or data-line which has to be protected. As long as the voltage level on the data- or signal-line is between 0 V (ground level) and the specified maximum reverse working voltage (V_{RWM}) the protection diode between data line and ground offers a high isolation to the ground line. The protection device behaves like an open switch. As soon as any positive transient voltage signal exceeds the break down voltage level of the protection diode, the diode becomes conductive and shorts the transient current to ground. Now the protection device behaves like a closed switch. The

Any negative transient signal will be clamped accordingly. The negative transient current is flowing in the forward direction of the protection diode. The low forward voltage (V_F) clamps the negative transient close to the ground level.

clamping voltage (V_C) is defined by the break down voltage (V_{BR}) level plus the voltage drop at the series impedance (resistance

Due to the different clamping levels in forward and reverse direction the VESD05B1-02V clamping behavior is bidirectional and asymmetrical (BiAs).





PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines
Reverse stand off voltage	Max. reverse working voltage	V_{RWM}	=	-	5	V
Reverse voltage	at I _R = 0.1 μA	V_R	5	-	-	V
Reverse current	at V _R = 5 V	I _R	-	0.01	0.1	μΑ
Reverse breakdown voltage	at I _R = 1 mA	V_{BR}	6	6.8	7.5	V
Reverse clamping voltage	at $I_{PP} = 1 \text{ A}$, $t_p = 300 \mu\text{s}$	V _C	-	7.2	9.5	V
	at $I_{PP} = I_{PPM} = 3.5 \text{ A}$, $t_p = 8/20 \mu\text{s}$	V _C	-	8.6	11	V
Forward clamping voltage	at $I_{PP} = 0.2 \text{ A}$, $t_p = 300 \mu\text{s}$	V_{F}	-	0.95	1.2	V
	at $I_{PP} = 1 \text{ A}$, $t_p = 300 \mu\text{s}$	V_{F}	-	1.3	-	V
	at I _{PP} = I _{PPM} = 3.5 A, t _p = 300 μs	V _F	-	1.9	-	V
Dynamic resistance	t _p = 100 ns (TLP); pin 1-2		-	0.2	-	Ω
	t _p = 100 ns (TLP); pin 2-1	r _{dyn}	-	0.31	-	Ω
Capacitance	at V _R = 0 V; f = 1 MHz	C _D	-	19	23	pF
	at V _R = 2.5 V; f = 1 MHz	C _D	-	12	-	pF

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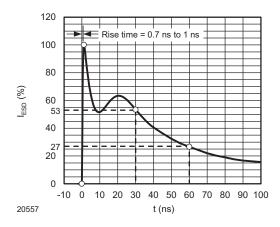


Fig. 1 - ESD Discharge Current Wave Form acc. IEC 61000-4-2 (330 Ω / 150 pF)

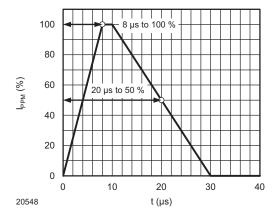


Fig. 2 - 8/20 µs Peak Pulse Current Wave Form acc. IEC 61000-4-5

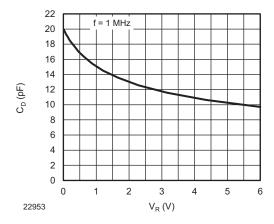


Fig. 3 - Typical Capacitance vs. Reverse Voltage

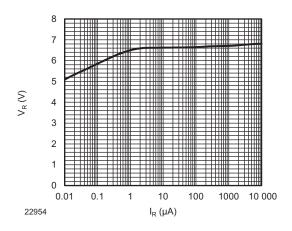


Fig. 4 - Typical Reverse Voltage vs. Reverse Current

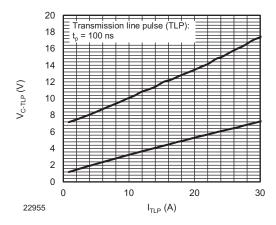


Fig. 5 - Typical Clamping Voltage vs. Peak Pulse Current

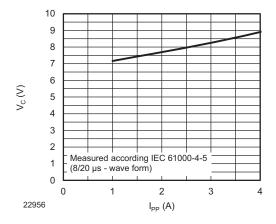
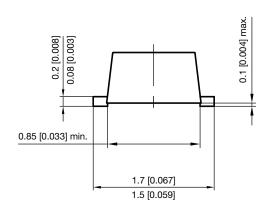
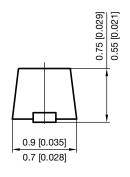


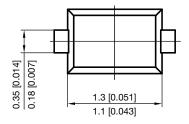
Fig. 6 - Typical Peak Clamping Voltage vs. Peak Pulse Current

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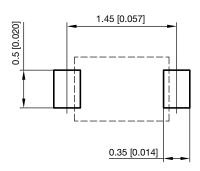
PACKAGE DIMENSIONS in millimeters (Inches): SOD-523







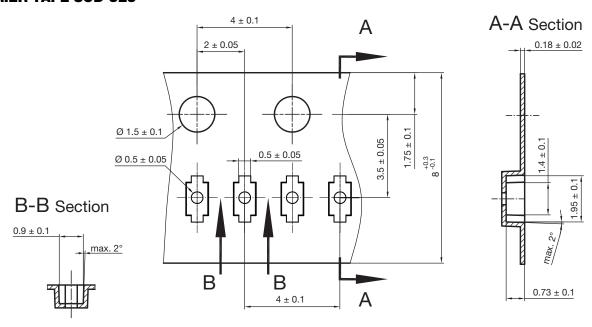
foot print recommendation:



Document no.: S8-V-3880.02-003 (4) Created - Date: 04. April 2017 Rev. 3 - Date: 27. May 2019

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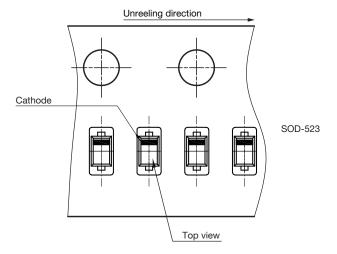
CARRIER TAPE SOD-523



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ORIENTATION IN CARRIER TAPE SOD-523



S8-V-3717.03-006 (4) 05.07.2018 22958



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